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Electronic Supplementary Information

Chainmail Catalyst of Ultrathin P-doped Carbon Shell Encapsulated Nickel

Phosphides on Graphene towards Robust and Efficient Hydrogen Generation

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1. Preparation of Materials:

All chemicals were used as received. NiCl₂· $6H_2O$, NaH₂PO₂·H2O, *N*, *N*-Dimethylformamide (DMF), KOH and concentrated H₂SO₄ were purchased from *Sinopharm Chemical Reagent Co., Ltd.* DI water was obtained at 18.2 Ω . In a typical experiment, NiCl₂· $6H_2O$ (2mmol, 0.475g), NaH₂PO₂·H₂O (1 mmol, 0.106 g) and GO solution (12 mg mL⁻¹, 3.5 mL) were homogeneously dispersed in a mixture solvent of 10 mL DI water and 10 mL DMF. After vigorously stirring and ultrasonication for 30 min, respectively, the mixture was poured into Teflon-lined stainless steel autoclave (50 mL), then the sealed autoclave was maintained at 160°C for 16h. When the reaction finished, the autoclave could naturally cool down to room temperature. The black precipitates were collected by centrifuge, washed by DI water and absolute ethanol each for three time to remove the unreacted reactants and soluble impurities. Finally, the as-prepared sample was freeze dried overnight. The as-prepared precursor in quartz boat was placed in an evacuated quartz tube furnace and annealed under reducing atmosphere (the flow ratio of Ar and H₂ was 45:5) at 500 °C for 4h with a heating rate of 5°C/min, then the quartz tube furnace could naturally cool down to room temperature. The contrast material Ni₂P MS was synthesized without adding GO solution. Ni₂P/C was fabricated by replacing GO solution with XC-72R.

2. Characterization.

X-ray diffraction (XRD) patterns was conducted on a PANalytical B.V. x'pert3 powder X-ray diffractometer with Cu K α radiation (λ =1.5405Å) at 30 kV and 20 mA from 10° to 80° with a scanning increment of 0.02°. Scanning electron microscopy (SEM) and energy-dispersive X-ray analysis (EDX) were conducted with a field-emission scanning electron microscope (FESEM, Nova NanoSEM 450) at an accelerating voltage of 10 kV. Transmission electron microscopy (TEM) and high-resolution transmission electron microscopy (HR-TEM) images were obtained with a Tecnai G2 20 scope at an acceleration voltage of 200 kV. High-angle annular dark field (HAADF) imaging and energy-dispersive spectrometry (EDS) elemental mapping analysis were performed in scanning transmission electron microscopy (STEM) mode on

an aberration-corrected FEI Titan G2 60-300 field emission transmission electron microscope, operated at 300 kV ($\alpha_{max} = \sim 100$ mrad). Raman spectra were recorded on a LabRAM HR800 instrument with a Nd: YAG laser source of 532 nm in a macroscopic configuration. All XPS spectra were collected by a monochromatic Al-K α X-ray source (hv = 1486.6 eV, Kratos, AXIS-ULTRA DLD-600W). Inductively coupled plasma mass spectrometer (ICP-MS) were obtained from PerkinElmer ELAN DRC-e instrument.

3. Electrochemical measurement.

All electrochemical measurements were performed using an AutoLab (PGSTAT302N) electrochemical workstation with a typical three electrode system in electrolyte at 25°C. Ag/AgCl (saturated) and Hg/HgO was used as reference electrode in acid (0.5 M H₂SO₄, pH=0) and alkaline (1.0 M KOH, pH=13.6) electrolyte, respectively. Graphite rod was used as counter electrode. A glassy carbon electrode (GCE, diameter of 0.5 cm, 0.196 cm⁻² in area) covered with catalysts was used as working electrode which was prepared as follows: 5 mg of the as-prepared catalyst was dispersed in 500 μ L of ethanol containing 0.25% Nafion, then assisted with sonication treatment for at least 30 min to get a homogenous ink, 10 μ L ink was carefully dropped onto the GCE via micropipettor, and the electrode was allowed to dry at room temperature. The mass loading of the electrode was calculated to be 0.51 mg cm⁻². Before test, the electrolyte was purged with N₂ gas.

Linear sweep voltammograms (LSVs) in acid (0.5 M H₂SO₄) and in alkaline (1.0 M KOH) electrolyte were recorded from 0V to -0.5 V (vs. RHE) at a scan rate of 5 mV s⁻¹. All potentials were referenced to a reversible hydrogen electrode (RHE) with 90% iR correction: $E_{vs.RHE} = E_{vs.Ag/AgCl} + 0.197 + 0.059pH - iR$, $E_{vs.RHE} = E_{vs.Hg/HgO} + 0.098 + 0.059pH - iR$, where the R was referred to the average ohmic resistance obtained from EIS measurement. Electrochemical Impedance Spectroscopy (EIS) were measured at -0.15 V (vs. RHE) with the AC voltage amplitude of 5 mV and the frequency range from 10⁵ Hz to 0.1 Hz. Cyclic voltammograms (CVs) were recorded from 0.097 V to 0.197 V (vs. RHE, -0.1 V~ 0 V vs Ag/AgCl) at different scan rates. These CV curves within non-faradaic region centered at the open circuit potential (OCP) with a potential window of 0.1 V are recorded to estimate the double layer capacitance (C_{dl}) of the catalysts. The long term stability of the catalysts characterized by continuous cyclic voltammograms was recorded from 0V to -0.5 V (vs. RHE) at 100 mV s⁻¹. The extended durability was also characterized by chronopotentiometric test with a constant current density at -10 mA cm⁻² for 25 h.

The effective electrochemical active surface area (ECSA) of the catalysts is calculated according to the equation ECSAs = C_{dl}/C_s , where Cs is the specific capacitance of the material or the capacitance of an atomically smooth planar surface of the material per unit area under identical electrolyte conditions, here, we use general specific capacitances of Cs = 0.04 mF cm⁻² in 1.0 M KOH according to recent reports.¹⁻³ The turnover frequency (TOF) was calculated according to the equation: $TOF=\frac{jS}{2nF}$. Where *j* is the current density at an overpotential of -150 mV, S is the geometric surface area of GC electrode (0.196 cm²), 2 stands for a two electron reaction process in HER, F is Faraday constant (96,485.3 mol/C), n is the number of moles of metal atoms deposited onto the GC electrodes that calculated from mass loading (0.51 mg cm⁻², the molar mass of Ni₂P: 148.35) and ICP-MS results (every metal atom is regard as being able to catalyze the reaction).^{2,4}

The kinetic current density for HER was fitted with simplified Butler–Volmer equation:

$$j_k = j_0 (e^{\frac{\alpha F}{RT}\eta} - e^{-(\frac{1-\alpha}{RT})\eta})$$

Where j_0 is the exchange current density obtained from the intersection between extrapolated Tafel plot and X axis. α is the transfer coefficient (set as 0.5) with respect to the symmetry of the HER/HOR, which set as 0.5, in accordance with literature. F, R, and T are Faraday's constant (96485 C mol⁻¹), the universal gas constant (8.314 J mol⁻¹ K⁻¹), and the temperature in Kelvin (around 298 K), respectively. η is the applied overpotential (in V).

Note: the calculation of interfacial angle:

According to literature, the interfacial angle of hexagonal crystal system (hcp) can be calculated as:⁵

$$\cos \Phi = \frac{h_1 h_2 + k_1 k_2 + \frac{1}{2} (h_1 1 k_2 + h_2 k_1) + \frac{3a^2}{4c^2} l_1 l_2}{\sqrt{(h_1^2 + k_1^2 + h_1 k_1 + \frac{3a^2}{4c^2} l_1^2)(h_2^2 + k_2^2 + h_2 k_2 + \frac{3a^2}{4c^2} l_2^2)}}$$

Where $(h_1, k_1, l_1) = (1, 1, 1)$, $(h_2, k_2, l_2) = (2, 1, 0)$, a=b=5.86, and c=3.37.

4. DFT calculation

The density functional theory (DFT) calculations were performed using the plane-wave technique implemented in the Vienna ab initio Simulation package (VASP).⁶ The electron-ion interactions were described by the projector-augmented plane wave (PAW) pseudopotentials.^{7,8} The revised Perdew-Burke-Ernzerhof (RPBE) functional was used for the exchange and correlation term. The dispersion correction of the D3 correction method by Grimme et al. was also included.^{9,10} A plane-wave cutoff energy was set to 470 eV and the spin-polarization was adopted for all computations. The convergences of energy and forces were taken as 10^{-4} eV and 0.05 eV/Å, respectively. All the atoms are free to relax during the structure optimization. The $7 \times 7 \times 13$ Monkhorst-Pack grid k-points were employed for the structure optimization of unit cell of Ni₂P, while the gamma k-points was adopted for others since the system is quite large.

The free energy of H adsorption (ΔG_{H^*} , H^{*} means an adsorbed H atom) is computed to evaluate the HER activity of each system and can be obtained by

$$\Delta G_{H^*} = \Delta E_{H^*} + \Delta E_{ZPE} - T\Delta S \tag{1}$$

where the ΔE_{H^*} , ΔE_{ZPE} , and ΔS are the binding energy, zero-point energy (ZPE) change, and entropy change of adsorption H, respectively.^{11,12} The value of ΔE_{ZPE} -T ΔS term is near 0.24 eV and thus ΔG_{H^*} is calculated by $\Delta E_{H^*} + 0.24$ eV in this work.¹³

A $1 \times 1 \times 2$ supercell of Ni₂P encapsulated in a carbon shell (labeled as Ni₂P@C) was built first. For the structure model of hexagonal Ni₂P structure, the calculated cell parameters are a = b = 5.862 Å, and c = 3.372 Å, which is in good agreement with the experimental value (a = b = 5.86 Å and c = 3.37 Å). The model of carbon shell is constructed as C180 (a = b = 2.46 Å, c = 2.8Å) comprising 180 C atoms. The differential charge density was computed to determine the possible adsorption sites. The differential charge density of Ni1-4-8 region is similar with Ni2-3-2, which indicates that the HER activity of these four sites (sites 2, 3, 4 and 8)

would be similar. As a result, the sites 4 and 6, which could show different HER activity, are chosen to be the possible H adsorption and P doped sites, respectively. Moreover, since there is a significant charge transfer from Ni1 to site 4 compared with site 6, the atomic charge of site 4 should be smaller than site 6, which is proved by the Bader analysis and listed in Table S4 (-0.08 for site 4 and -0.01 for site 6).

According to the atomic charge of Ni₂P@C H' and Ni₂P@C H" (H' and H" represent H* adsorbed on site 4 and site 6, respectively), the C site with adsorbed H would transfer their electrons to neighboring C atoms after the H adsorption, which leads to the positively charged H (0.09 for Ni₂P@C H', 0.04 for Ni₂P@C H") and the increased atomic charge of the adsorbing C. As a result, the atomic charge of site 4 with H adsorption is -0.01e, while the charge of site 6 with H adsorption is 0.06e. Herein, the charge interaction between site 4 and H' (-0.01e for site 4 and 0.09e for H') is stronger than that between site 6 and H" (0.06e for site 6 and 0.04e for H"), which causes smaller ΔG_{H^*} of Ni₂P@C H' than Ni₂P@C H". The similar mechanism also takes place in Ni₂P@PC. In general, the doped P atom could transfer its electrons to its adjacent atoms, including the adsorbed H. The charge of H" in Ni₂P@PC (-0.40e) is negative, while the charge of H' in Ni₂P@PC (0.08e) is positive. Therefore, the interaction between H' and site 4 is stronger than between H" and site 6 for Ni₂P@PC which is consistent with the order of corresponding ΔG_{H^*} value.

Figures and Tables



Figure S1. The (a) TEM image of $Ni_2P@rGO$ and (b) The statistical particle size distribution of 100 particles in (a).



Figure S2. (a-c) SEM images of Ni-P/C: (a, b) precursor, (c) annealed Ni₂P/C. (d-f) Ni-P microspheres: (d, e) precursor, (f) annealed Ni₂P MS.



Figure S3. SEM images of precursors with different GO concentration. (a) 0.9 mg mL^{-1} ; (b) 1.8 mg mL^{-1} ; (c) 3.6 mg mL^{-1} . (d) The corresponding HER performance of various materials in $0.5 \text{ M H}_2\text{SO}_4$ (scan rate: 5mV/s).



Figure S4. The precursor annealed under different temperature. (a) 300 °C, (b) 400 °C, (c) 500 °C, (d) 750 °C. (e) The powder XRD pattern of the as-prepared materials. (f) The corresponding HER performance of various materials in 0.5 M H₂SO₄ (scan rate: 5mV/s).



Figure S5. The precursor annealed under 500 °C for different duration. (a) 2h, (b) 4h, (c) 8h. (d) The corresponding HER performance of various materials in $0.5 \text{ M H}_2\text{SO}_4$ (scan rate: 5mV/s).



Figure S6. The HR-TEM images of materials annealed under 500 °C for different duration. (a) 2h, (b) 4h, (c) 8h. As we can see from these figures that with the increase of annealing time, the carbon shell outside the Ni₂P core is getting thicker, with 4h be the moderate 2~5 layers, which show optimum performance toward HER, as shown in Figure S4d, in consistent with literature.



Figure S7. The comparison of different products with different NiCl₂• $6H_2O$ content involved. Sample-1: half NiCl₂• $6H_2O$ and Sample-3: double NaH₂PO₂• H_2O . SEM images of (a) precursor and (b) annealed Sample-1. SEM images of (c) precursor and (d) annealed Sample-3. (e) The corresponding HER performance of various materials in 0.5 M H₂SO₄ (scan rate: 5mV/s).



Figure S8. (a) SEM and (b) EDX elemental contents of Ni₂P@PCG, (c) the elemental mapping images of

C, O, Ni and P.



Figure S9. XPS survey spectra of precursor and Ni₂P@PCG (a) Full spectrum and (b) High-resolution XPS spectra of O 1s of precursor. (c) Full spectrum and (d) High-resolution XPS spectra of O 1s of Ni₂P@PCG.



Figure S10. Comparison of XPS survey spectra of Ni₂P@PCG, Ni₂P/C and Ni₂P MS. (a) Ni 2p, (b) P 2p, (c) C 1s.



Figure S11. The characterization of post-test material. (a) XRD pattern. (b) SEM and (c) TEM images. (d)

HR-TEM image.



Figure S12. The XPS survey of post-test material. (a) Full spectrum, and High-resolution spectra of (b) C 1s, (c) P 2p and (d) Ni 2p.



Figure S13. HER performance in 1.0 M KOH. (a) LSV curves (b) Tafel plots, (c) stability test at 10 mA cm⁻² for 25h, the inset show LSV curves of Ni₂P@PCG before and after 5000 cycles, (d) EIS Nyquist plots at -0.3 V (*vs.* RHE).



Figure S14. (a) Equivalent circuit used to model the HER process on Ni₂P@PCG at various overpotentials.
(b) Nyquist plots of the impedance data of Ni₂P@PCG for HER in 0.5 M H₂SO₄. (c) The plot of overpotential *vs.* log (1/R_{ct}) and its linear fitting.



Figure S15. Non-faradaic CV scans of various electrocatalysts at 0.097~0.197 V vs RHE (-0.1~0 V vs Ag/AgCl) in 0.5 M H₂SO₄.



Figure S16. (a) Capacitive currents-scan rates plots of various electrocatalysts at 0.15 V *vs.* RHE. (b) The ECSA of Ni₂P@PCG, Ni₂P/C, Ni₂P MS. (c) LSV curves of the catalysts normalized by ECSAs. (d) The TOF calculated at an overpotential of -150 mV (the contents of Ni₂P in Ni₂P@PCG and Ni₂P/C were 53.7% and 35%, respectively, obtained from ICP-MS).



Figure S17. The LSV curves of kinetic current density for HER, fitted with simplified Butler–Volmer equation.



Figure S 18. (a) The original structure of Ni₂P@C. (b) Magnified diagram of differential charge density of the region in dashed black circle of (a). The yellow and cyan regions represent electron flow in and flow out. The isosurface value in (b) is 0.005 e/bohr³. Brown: C, grey blue: Ni, grey violet: P.



Figure S19. Theoretical models of the studied systems: The optimized structure of H adsorption and their ΔG_{H^*} value. Structures of H adsorbed on 4 (H') and 6 site (H") of (a-b) Ni₂P@C, (c-d) Ni₂P@PC. The insert figures are the corresponding differential charge density with isosurface value of 0.005 e/bohr³. Brown: C, grey blue: Ni, grey violet: P, red: H.

Samples	С	0	Р	Ni
Ni-P/GO	39.15	39.72	10.96	10.17
Ni2P@PCG	67.92	20.38	6.56	5.14
Ni ₂ P MS	14.73	38.22	16.53	30.52
Ni ₂ P/C	73.36	18.55	4.13	3.96

Table S1. Elemental contents of materials (atomic ratio), obtained from XPS survey.

Electrocatalyst	Mass	Current density	Overpotential	Exchange	Electrolyte	Ref.
	loading	(mA/cm ²)	(mV)	current		
	(mg/cm ²)			density		
				(mA/cm ²)		
Ni ₂ P@PCG	0.51	10	110	0.13	0.5 M	This work
					H ₂ SO ₄	
			150		1.0 M KOH	This work
Ni ₂ P/Ti	1.0	20	130	/	0.5 M	J. Am. Chem. Soc.
					H_2SO_4	2013 , <i>135</i> , 9267
			205		1.0 M KOH	
Ni ₂ P/Ni	-	10	128	/	0.5M H ₂ SO ₄	ACS Appl. Mater.
			183		1.0 M KOH	Interfaces 2016 , 8,
						12798
Ni ₂ P/GCE	0.38	20	140	/	1 M H ₂ SO ₄	Phys. Chem. Chem.
			250		1.0 M KOH	Phys. 2014, 16, 5917
Ni ₂ P/CNT	-	10	124	0.0537	0.5 M	J. Mater. Chem. A
					H_2SO_4	2015 , <i>3</i> , 13087
Ni ₂ P NPs	1.99	10	137	0.04592	0.5 M	J. Mater. Chem. A
					H_2SO_4	2015 , <i>3</i> , 1656
MOF-derived	0.35	10	~200	0.071	0.5 M	RSC Adv. 2015, 5,
Ni ₂ P					H_2SO_4	10290
CoP NCs	0.28	100	~180	/	0.5 M	Nano Lett. 2015 , 15,
					H_2SO_4	7616.
CoP@SNC	0.61	10	174	/	1.0 M KOH	Nanoscale 2018 , 10,
						14613
CoNi	1.6	10	142	/	0.1 M	Angew. Chem. Int. Ed.
nanoalloy					H_2SO_4	2015 , <i>54</i> , 2100

 Table S2. Comparison of typical Ni₂P based electrocatalysts for HER.

Table S3. Atomic charge of some atoms which near the adsorbed H on site 4(H') or site 6(H'') of the systems. The location of these sites and adsorbed H are depicted in Figure S12.

Charge / e	1	2	3	4	5	6	7	8	Н
Ni ₂ P@C	-0.08	-0.11	-0.06	-0.08	0.04	-0.01	-0.01	-0.11	
Ni ₂ P@C H'	0.04	-0.08	-0.13	-0.01	-0.01	-0.08	0.00	-0.14	0.09
Ni ₂ P@C H"	-0.08	-0.12	-0.06	-0.10	0.02	0.06	-0.04	-0.13	0.04
Ni ₂ P@PC	-0.53	-0.11	-0.54	-0.59	-0.05	1.49	-0.04	-0.06	_
Ni ₂ P@PC H'	-0.62	-0.14	-0.55	-0.38	-0.04	1.42	-0.07	-0.10	0.08
Ni ₂ P@PC H"	-0.75	-0.09	-0.77	-0.75	-0.06	2.51	-0.05	-0.12	-0.40

Table S4. The binding energy (ΔE_{H^*}) and free energy of H adsorption (ΔG_{H^*}) for H adsorbed on site 4 or site 6 of Ni₂P@C, Ni₂P@PC (P doped on site 6) and C₁₈₀.

Structure	Site	ΔE_{H^*} / eV	$\Delta G_{\mathrm{H}^*}/~\mathrm{eV}$
Ni ₂ P@C	C4	-0.005	0.235
Ni ₂ P@C	C6	0.372	0.612
Ni ₂ P@PC	C4	-0.306	-0.066
Ni ₂ P@PC	P6	-0.411	-0.171
С	C4	0.560	0.800
С	C6	0.903	1.143
Ni ₂ P		_	-0.54 (J. Am. Chem. Soc.
			2013 , <i>135</i> , 9267)

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